

HE8812SG

GaAlAs Infrared Emitting Diode

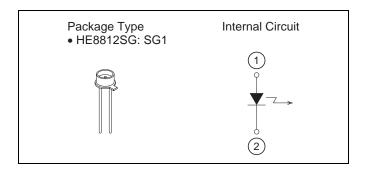
ODE2063-00 (M) Rev.0 Aug. 01, 2008

Description

The HE8812SG is a GaAlAs double heterojunction structure 870 nm band light emitting diode. It is suitable for use as the light source in a wide range of optical control and sensing equipment.

Features

• High efficiency and high output power



Absolute Maximum Ratings

 $(T_C = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Forward current	I _F	250	mA
Reverse voltage	V _R	3	V
Operating temperature	Topr	-20 to +60	°C
Storage temperature	Tstg	-40 to +90	°C

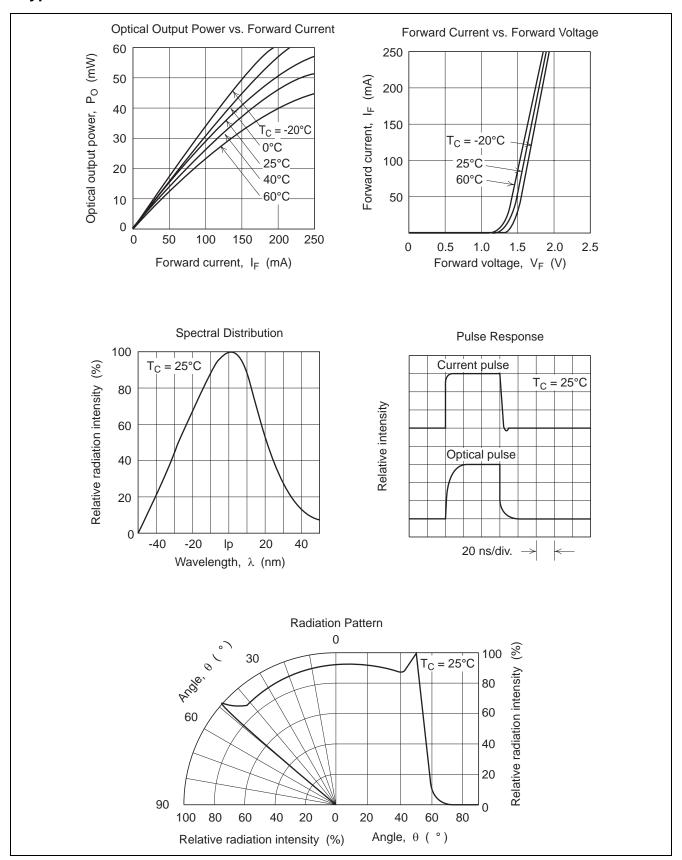
Optical and Electrical Characteristics

 $(T_C = 25^{\circ}C)$

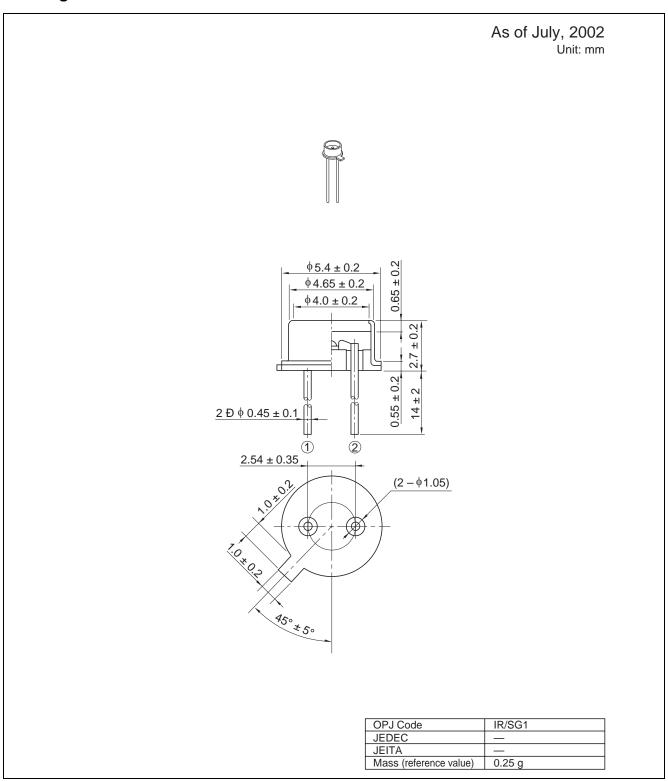
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Optical output power	Po	40	_	_	mW	I _F = 200 mA
Peak wavelength	λρ	840	870	900	nm	I _F = 200 mA
Spectral width	Δλ	_	50	60	nm	I _F = 200 mA
Forward voltage	V _F	_	_	2.5	V	I _F = 200 mA
Reverse current	I _R	_	_	100	μΑ	V _R = 3 V
Capacitance	Ct	_	30	_	pF	$V_R = 0 V, f = 1 MHz$
Rise time	t _r	_	10	_	ns	I _F = 50 mA
Fall time	t _f	_	10	_	ns	I _F = 50 mA



Typical Characteristic Curves



Package Dimensions



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- 1. The laser light is harmful to human body especially to eye no matter what directly or indirectly. The laser beam shall be observed or adjusted through infrared camera or equivalent.
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Sales Offices



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